

# MSKSEMI 美森科

SEMICONDUCTOR



ESD



TVS



TSS



MOV



GDT



PLED


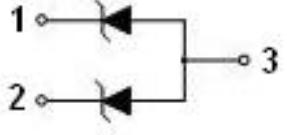
## AZ23C2V7-AZ23C39

Product specification

**FEATURES**

- Dual zeners in common anode configuration.
- 300mW power dissipation rating.
- Ideally suited for automatic insertion.
- $\Delta V_z$  for both diodes in one case is  $\leq 5\%$ .
- Common cathode style available see DZ series.
- Also available in lead free version

**Reference News**

PACKAGE OUTLINE	PIN CONFIGURATION
	
SOT-23	

**Maximum Ratings(Ta=25 °C unless otherwise specified)**

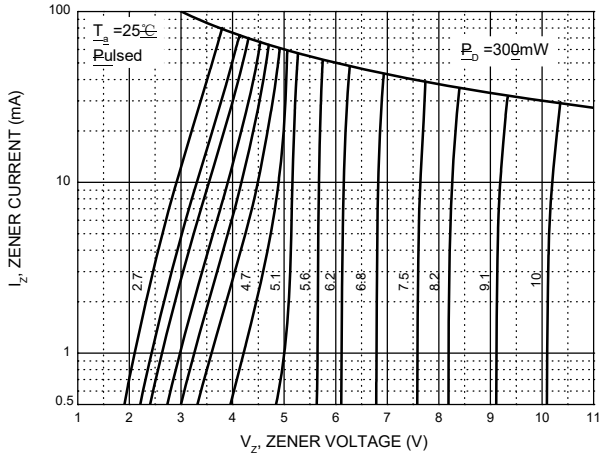
Characteristic	Symbol	Value	Unit
Forward Voltage @ I <sub>F</sub> = 10mA	V <sub>F</sub>	0.9	V
Power Dissipation	P <sub>D</sub>	300	mW
Thermal Resistance from Junction to Ambient	R <sub>θJA</sub>	417	°C/W
Operation Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55~+150	°C

**ELECTRICAL CHARACTERISTICS**
**T<sub>a</sub>=25°C unless otherwise specified**

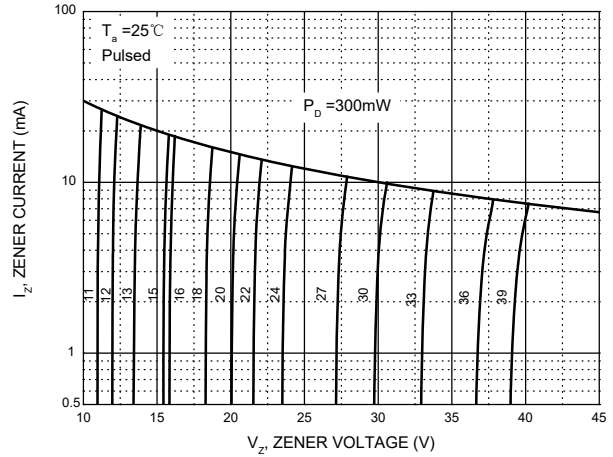
Type Number	Marking Code	Zener Voltage Range (note1)	Maximum Zener Impedance (note 2)		Typical Temperature Coefficient	Min Reverse Voltage (note1)
		@ I <sub>ZT</sub> =5.0mA	Z <sub>ZT</sub> @I <sub>ZT</sub> =5.0mA	Z <sub>Zk</sub> @I <sub>Zk</sub> =1.0mA		@I <sub>R</sub> =0.1 μA
		V <sub>Z</sub> (V)	Ω	Ω	T <sub>c</sub> (%/°C)	V <sub>R</sub> (V)
AZ23C2V7	KD1	2.5-2.9	83	500	-0.065	–
AZ23C3V0	KD2	2.8-3.2	95	500	-0.060	–
AZ23C3V3	KD3	3.1-3.5	95	500	-0.055	–
AZ23C3V6	KD4	3.4-3.8	95	500	-0.055	–
AZ23C3V9	KD5	3.7-4.1	95	500	-0.050	–
AZ23C4V3	KD6	4.0-4.6	95	500	-0.035	–
AZ23C4V7	KD7	4.4-5.0	78	500	-0.015	–
AZ23C5V1	KD8	4.8-5.4	60	480	+0.005	0.8
AZ23C5V6	KD9	5.2-6.0	40	400	+0.020	1.0
AZ23C6V2	KDA	5.8-6.6	10	200	+0.030	2.0
AZ23C6V8	KDB	6.4-7.2	8.0	150	+0.045	3.0
AZ23C7V5	KDC	7.0-7.9	7.0	50	+0.050	5.0
AZ23C8V2	KDD	7.7-8.7	7.0	50	+0.055	6.0
AZ23C9V1	KDE	8.5-9.6	10	50	+0.065	7.0
AZ23C10	KDF	9.4-10.6	15	70	+0.065	7.5
AZ23C11	KDG	10.4-11.6	20	70	+0.070	8.5
AZ23C12	KDH	11.4-12.7	20	90	+0.075	9.0
AZ23C13	KDI	12.4-14.1	25	110	+0.080	10.0
AZ23C15	KDJ	13.8-15.6	30	110	+0.080	11.0
AZ23C16	KDK	15.3-17.1	40	170	+0.090	12.0
AZ23C18	KDL	16.8-19.1	50	170	+0.090	14.0
AZ23C20	KDM	18.8-21.2	50	220	+0.090	15.0
AZ23C22	KDN	20.8-23.3	55	220	+0.090	17.0
AZ23C24	KDO	22.8-25.6	80	220	+0.090	18.0
AZ23C27	KDP	25.1-28.9	80	250	+0.090	20.0
AZ23C30	KDQ	28-32	80	250	+0.090	22.5
AZ23C33	KDR	31-35	80	250	+0.090	25.0
AZ23C36	KDS	34-38	90	250	+0.090	27.0
AZ23C39	KDT	37-41	90	300	+0.110	29.0

Notes: 1. Short duration test pulse used to minimize self-heating effect.  
 2. f=1kHz

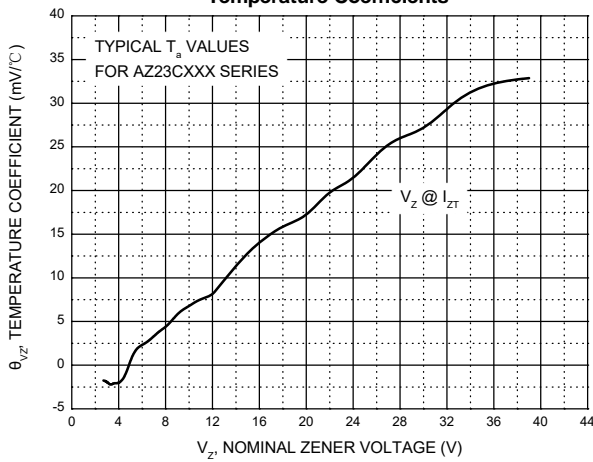
Zener Characteristics ( $V_z$  Up to 10 V)



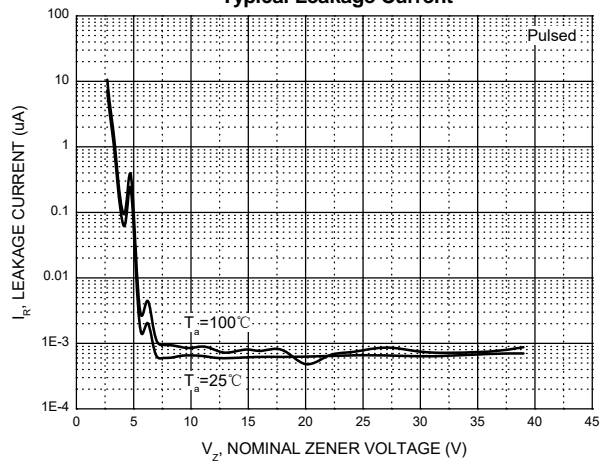
Zener Characteristics (11 V to 39 V)



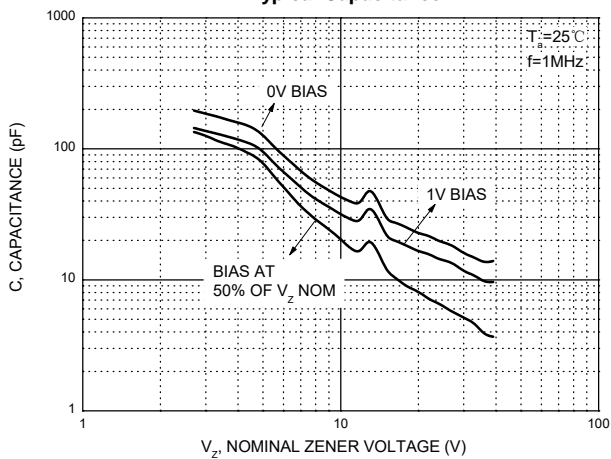
Temperature Coefficients



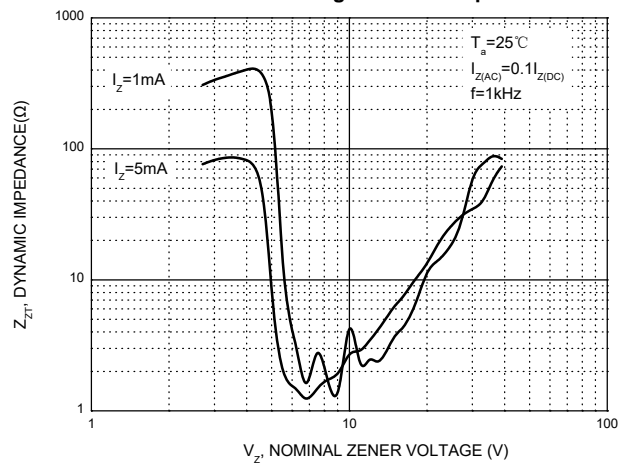
Typical Leakage Current



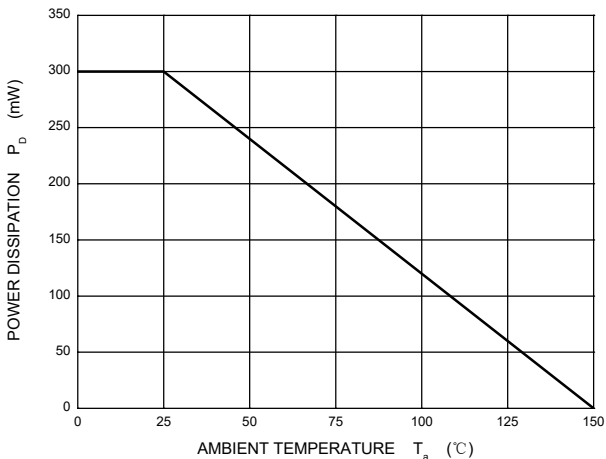
Typical Capacitance



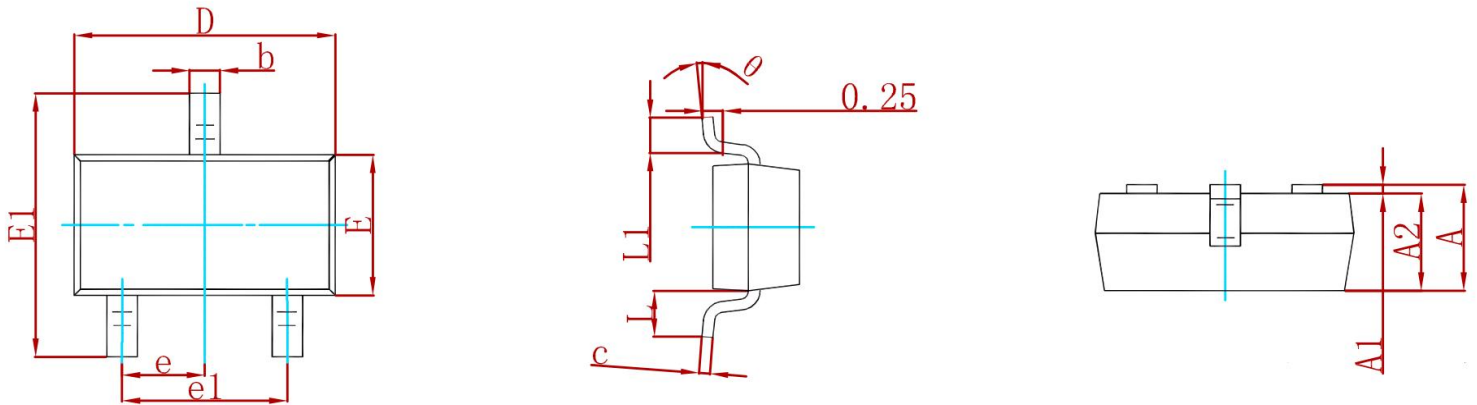
Effect of Zener Voltage on Zener Impedance



Power Derating Curve

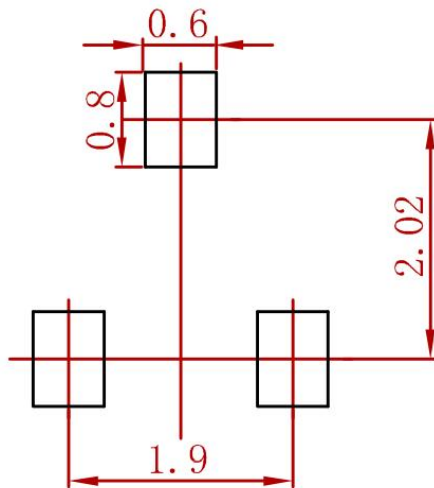


**PACKAGE MECHANICAL DATA**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

**Suggested Pad Layout**



**Note:**

1. Controlling dimension: in millimeters.
2. General tolerance: ±0.05mm.
3. The pad layout is for reference purposes only.

**REEL SPECIFICATION**

P/N	PKG	QTY
AZ23C2V7-AZ23C39	SOT-23	3000

## Attention

- Any and all MSKSEMI Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your MSKSEMI Semiconductor representative nearest you before using any MSKSEMI Semiconductor products described or contained herein in such applications.
- MSKSEMI Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all MSKSEMI Semiconductor products described or contained herein.
- Specifications of any and all MSKSEMI Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- MSKSEMI Semiconductor strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all MSKSEMI Semiconductor products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of MSKSEMI Semiconductor.
- Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. MSKSEMI Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringement of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the MSKSEMI Semiconductor product that you intend to use.

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [Zener Diodes](#) category:*

*Click to view products by [MSKSEMI](#) manufacturer:*

Other Similar products are found below :

[RKZ13B2KG#P1](#) [DL5234B](#) [EDZTE6113B](#) [1N4682](#) [1N4693](#) [1N4732A](#) [1N4736A](#) [1N4750A](#) [1N4759ARL](#) [1N5241B](#) [1N5365B](#) [1N5369B](#)  
[1N747A](#) [1N964B](#) [1N966B](#) [1N968B](#) [1N972B](#) [JANS1N4974US](#) [JANTX1N5907](#) [1N4692](#) [1N4700](#) [1N4702](#) [1N4704](#) [1N4711](#) [1N4714](#)  
[1N4745ARL](#) [1N4752ARL](#) [1N4760ARL](#) [1N5221B](#) [1N5242BTR](#) [1N5350B](#) [1N5352B](#) [1N961BRR1](#) [1N964BRL](#) [RKZ5.1BKU#P6](#)  
[3SMAJ5946B-TP](#) [3SMAJ5950B-TP](#) [3SMBJ5925B-TP](#) [MMSZ5230BQ-13-F](#) [MMSZ5232BQ-13-F](#) [BZX84C7V5](#) [3SMAJ5945B-TP](#)  
[3SMAJ5947B-TP](#) [3SMBJ5941B-TP](#) [DL4732A-T3](#) [DZ2S240M0L](#) [SMAZ27-TP](#) [ZMM5224B-7](#) [RD16UM-T1-A](#) [RD39S-T1-A](#)